

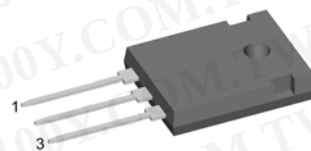
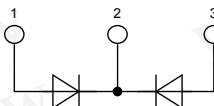
HiPerFRED²

High Performance Fast Recovery Diode
 Low Loss and Soft Recovery
 Common Cathode

Part number

DPG 30 C 300 HB

$$\begin{aligned} V_{RRM} &= 300 \text{ V} \\ I_{FAV} &= 2 \times 15 \text{ A} \\ t_{rr} &= 35 \text{ ns} \end{aligned}$$



Backside: cathode

Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low I_{rm} -values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low I_{rm} reduces:
 - Power dissipation within the diode
 - Turn-on loss in the commutating switch

Applications:

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

Package:

- Housing: TO-247
- Industry standard outline
- Epoxy meets UL 94V-0
- RoHS compliant

Ratings

Symbol	Definition	Conditions	min.	typ.	max.	Unit
V_{RRM}	max. repetitive reverse voltage	$T_{VJ} = 25^{\circ}\text{C}$			300	V
I_R	reverse current	$V_R = 300 \text{ V}$ $T_{VJ} = 25^{\circ}\text{C}$			1	μA
		$V_R = 300 \text{ V}$ $T_{VJ} = 150^{\circ}\text{C}$			0.08	mA
V_F	forward voltage	$I_F = 15 \text{ A}$ $T_{VJ} = 25^{\circ}\text{C}$			1.25	V
		$I_F = 30 \text{ A}$			1.50	V
		$I_F = 15 \text{ A}$ $T_{VJ} = 150^{\circ}\text{C}$			1.00	V
		$I_F = 30 \text{ A}$			1.27	V
I_{FAV}	average forward current	rectangular $d = 0.5$ $T_C = 140^{\circ}\text{C}$			15	A
V_{FO}	threshold voltage	$T_{VJ} = 175^{\circ}\text{C}$ for power loss calculation only			0.69	V
r_F	slope resistance				17.3	m Ω
R_{thJC}	thermal resistance junction to case				1.70	K/W
T_{VJ}	virtual junction temperature		-55		175	$^{\circ}\text{C}$
P_{tot}	total power dissipation	$T_C = 25^{\circ}\text{C}$			90	W
I_{FSM}	max. forward surge current	$t = 10 \text{ ms}$ (50 Hz), sine $T_{VJ} = 45^{\circ}\text{C}$			240	A
I_{RM}	max. reverse recovery current	$T_{VJ} = 25^{\circ}\text{C}$		3		A
		$I_F = 15 \text{ A}; V_R = 200 \text{ V}$ $T_{VJ} = 125^{\circ}\text{C}$		6.5		A
t_{rr}	reverse recovery time	$-di_F/dt = 200 \text{ A}/\mu\text{s}$ $T_{VJ} = 25^{\circ}\text{C}$		35		ns
		$T_{VJ} = 125^{\circ}\text{C}$		55		ns
C_J	junction capacitance	$V_R = 150 \text{ V}; f = 1 \text{ MHz}$ $T_{VJ} = 25^{\circ}\text{C}$		20		pF

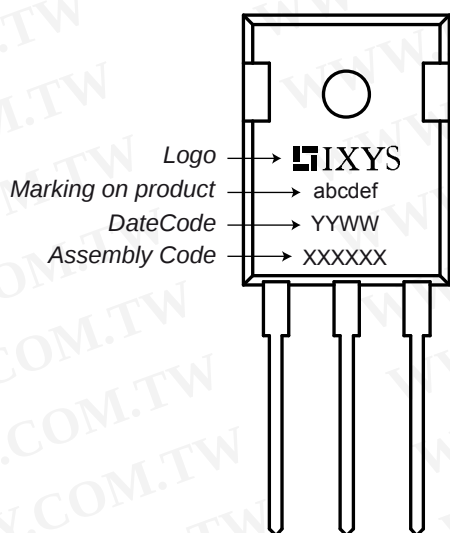
Symbol	Definition	Conditions	Ratings			
			min.	typ.	max.	Unit
I_{RMS}	RMS current	per pin ¹⁾			50	A
R_{thCH}	thermal resistance case to heatsink			0.25		K/W
T_{stg}	storage temperature		-55		150	°C
Weight				6		g
M_D	mounting torque		0.8		1.2	Nm
F_C	mounting force with clip		20		120	N

¹⁾ I_{RMS} is typically limited by: 1. pin-to-chip resistance; or by 2. current capability of the chip.

In case of 1, a common cathode/anode configuration and a non-isolated backside, the whole current capability can be used by connecting the backside.

勝特力材料 886-3-5753170
 勝特力电子(上海) 86-21-34970699
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[Http://www.100y.com.tw](http://www.100y.com.tw)

Product Marking



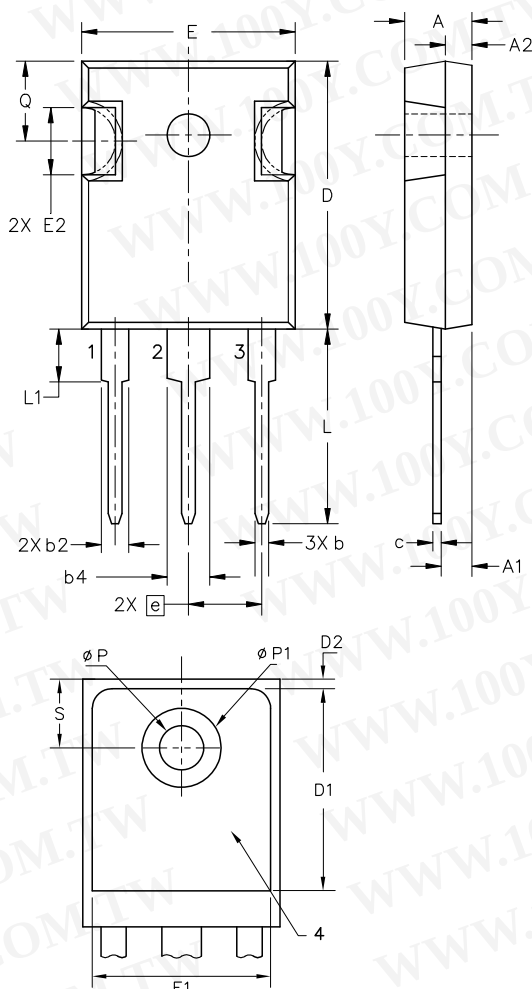
Part number

D = Diode
 P = HiPerFRED
 G = extreme fast
 30 = Current Rating [A]
 C = Common Cathode
 300 = Reverse Voltage [V]
 HB = TO-247AD (3)

Ordering	Part Name	Marking on Product	Delivering Mode	Base Qty	Code Key
Standard	DPG 30 C 300 HB	DPG30C300HB	Tube	30	502567

Similar Part	Package	Voltage Class
DPG30C300PB	TO-220AB (3)	300
DPG30C300PC	TO-263AB (D2Pak)	300

Outlines TO-247



Sym.	Inches		Millimeter	
	min.	max.	min.	max.
A	0.185	0.209	4.70	5.30
A1	0.087	0.102	2.21	2.59
A2	0.059	0.098	1.50	2.49
D	0.819	0.845	20.79	21.45
E	0.610	0.640	15.48	16.24
E2	0.170	0.216	4.31	5.48
e	0.215 BSC		5.46 BSC	
L	0.780	0.800	19.80	20.30
L1	-	0.177	-	4.49
Ø P	0.140	0.144	3.55	3.65
Q	0.212	0.244	5.38	6.19
S	0.242 BSC		6.14 BSC	
b	0.039	0.055	0.99	1.40
b2	0.065	0.094	1.65	2.39
b4	0.102	0.135	2.59	3.43
c	0.015	0.035	0.38	0.89
D1	0.515	-	13.07	-
D2	0.020	0.053	0.51	1.35
E1	0.530	-	13.45	-
Ø P1	-	0.29	-	7.39

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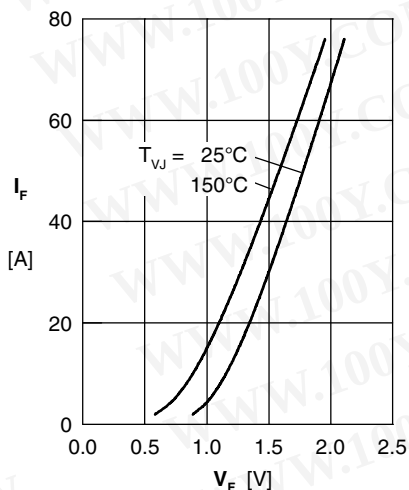
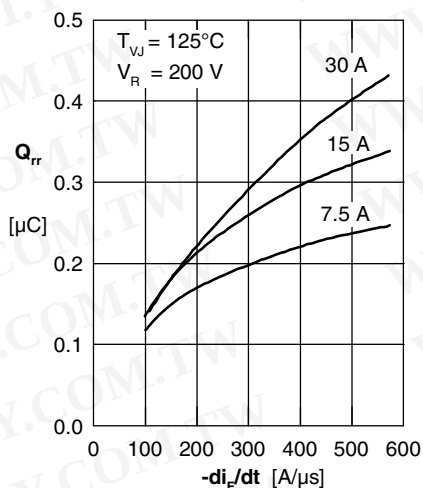
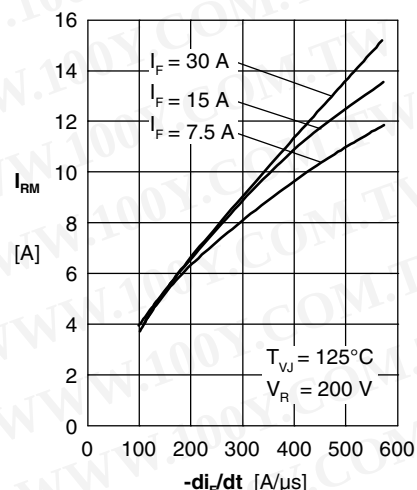
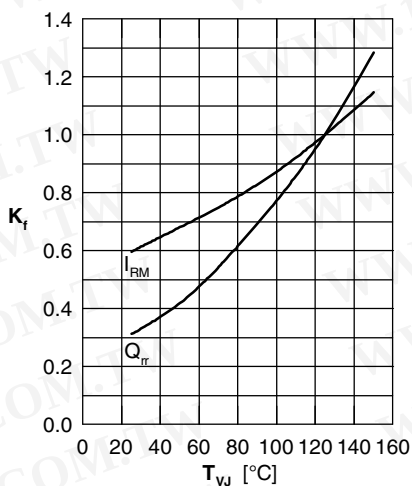
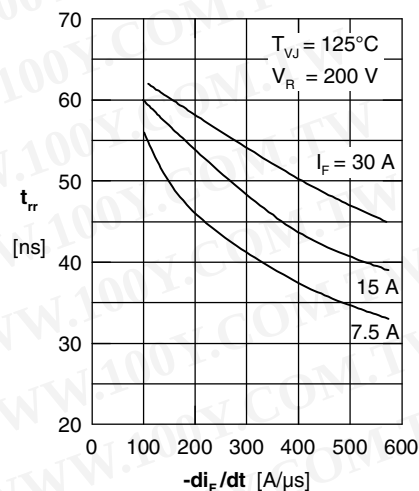
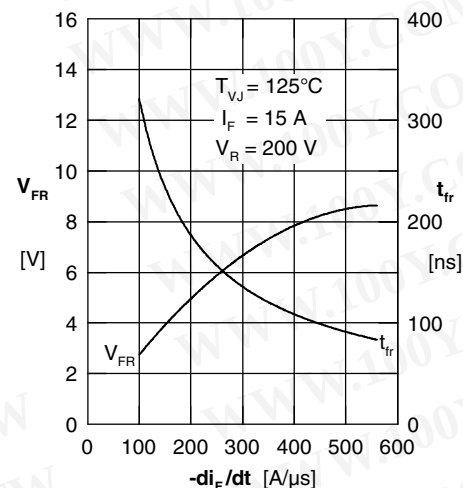
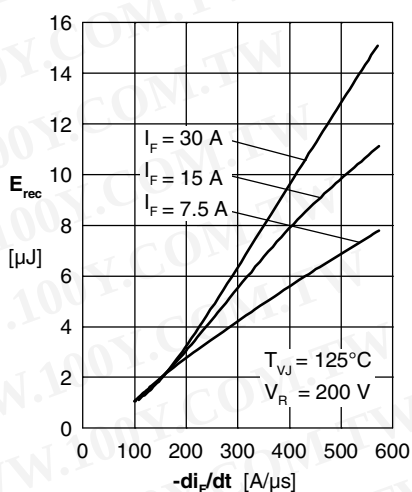
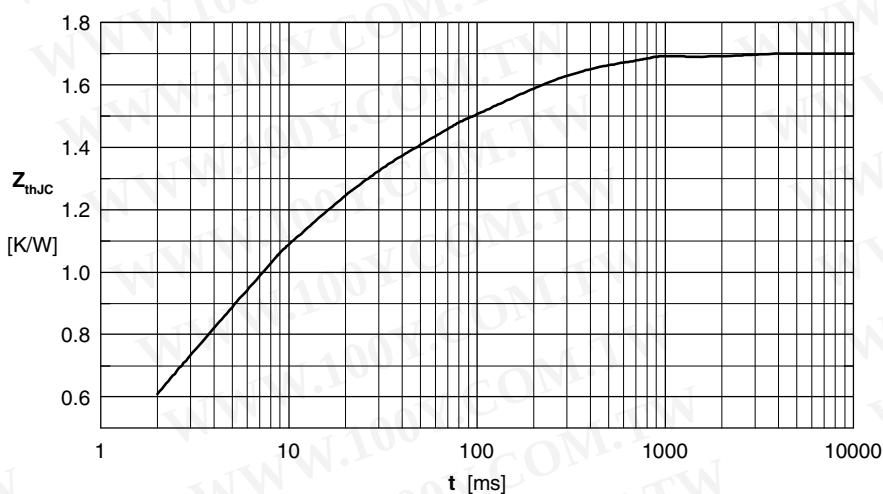
Fig. 1 Forward current I_F vs. V_F Fig. 2 Typ. reverse recovery charge Q_{rr} versus $-di_F/dt$ Fig. 3 Typ. peak reverse current I_{RM} versus $-di_F/dt$ Fig. 4 Dynamic parameters Q_{rr} , I_{RM} versus T_{VJ} Fig. 5 Typ. recovery time t_{rr} vs. $-di_F/dt$ Fig. 6 Typ. peak forward voltage V_{FR} and t_{rr} versus di_F/dt Fig. 7 Typ. recovery energy E_{rec} versus $-di_F/dt$ 

Fig. 8 Transient thermal resistance junction to case